

Surface Mount Low Barrier Schottky Diode

Rev. V13

Features

- Low I_R (<100 nA @ 1 V, <500 nA @ 3 V)
- Designed for High Volume, Low Cost Detector & Mixer Applications
- High Detector Sensitivity: -55 dBm TSS
- Low Capacitance: 0.30 pF
- Low 1/F Noise
- Single, Series Pair, and Unconnected Pair Configurations
- Lead Free
- RoHS* Compliant
- Tape and Reel

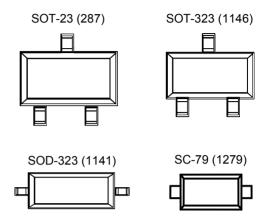
Description and Applications

The MA4E2054 series are low barrier N-type silicon Schottky diodes assembled in surface mount plastic packages. They are designed for use as high performance mixer and detector diodes.

The MA4E20541-1141T (SOD-323), MA4E20541-1279T (SC-79) and MA4E2054A1(SOT-23) are single element Schottky diodes characterized for use as single ended mixers and detectors. The MA4E2054B1 and MA4E2054D1 (available in both the SOT-23 and SOT-323 packages) incorporate two Schottky chips in series pair configurations. These diodes are useful for balanced mixer and detector voltage doubler circuits.

Applications for the MA4E2054 series include VSAT and DBS mixers. The small diode package size and low cost make them attractive for use in RF tag applications for identification and toll collection.

Package Outlines

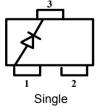


Part Numbers

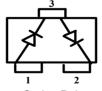
Part Number	Package Style
MA4E2054A1-287T	SOT-23
MA4E2054B1-287T	SOT-23
MA4E2054B1-1146T	SOT-323
MA4E2054D1-287T	SOT-23
MADS-002054-1146DT	SOT-323
MA4E20541-1141T	SOD-323
MA4E20541-1279T	SC-79

 The part number consists of the base chip (MA4E2054), followed by the wiring configuration (A, B, D, omit for SOD-323), the package style (287, 1141, 1146) and a "T" for tape and reel.

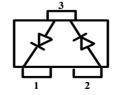
Configurations (Top View)



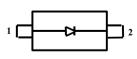
Single MA4E2054A1-287T



Series Pair MA4E2054B1-287T MA4E2054B1-1146T



Series Pair MA4E2054D1-287T MADS-002054-1146DT



Single MA4E20541-1141T MA4E20541-1279T

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



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Electrical Specifications @ +25°C^{2,3}

Parameter	Condition	Specification		
Breakdown Voltage (V _B)	I _R = 10 μA	3.0 V min.		
Reverse Leakage Current (I _R)	V _R = 1 V V _R = 3 V	100 nA max. 500 nA max.		
Total Capacitance (C _T)	$V_R = 0 V, F = 1 MHz$	0.3 pF max.		
Dynamic Resistance (R _D) ²	I _F = 10 mA	17 Ω max.		
Forward Voltage (V _F)	I _F = 1 mA	250 mV min. 350 mV max.		
Delta Forward Voltage(D V _F)	I _F = 1 mA	20 mV max.		

^{2.} Applies to MA4E2054B and MA4E2054D configurations.

Typical RF Performance @ +25°C in Chip Form, Mounted on a Microstrip Fixture

Parameter	Condition	Specification	
Mixer Noise Figure	F = 9.375 GHz, LO = 0 dBm	5.7 dB (SSB)	
IF Impedance	I _F = 30 MHz	200 ohms	
Tangential Signal, Sensitivity	$F = 2.5 \text{ GHz}$, $I_F = 20 \text{ mA}$, $BW = 2 \text{ MHz}$, $Video NF = 1.5 \text{ dB}$	-55 dBm	
Detector Output, Voltage at -30 dBm	R_L = 100 k Ω , I_F = 20 mA	20 mV	
Detector Output, Voltage at -30 dBm	R_L = 1 M Ω , Zero Bias	20 mV	

^{4.} See Performance Curves on page 4 for untuned fixture performance.

Maximum Ratings @ 25°C (unless otherwise specified)^{5,6}

Parameter	Values		
Operating Temperature	-65°C to +125°C		
Storage Temperature	-65°C to +125°C		
RF Incident Power (CW)	75 mW ⁷		
Forward Current	20 mA		
Reverse Voltage	3 V		
Soldering Temperature	+260°C for 5 sec.		

^{5.} Operation of this device above any one of the Maximum Rated parameters may cause permanent damage.

^{3.} $R_D = R_S + R_J$ where $R_J = \frac{26}{L}$ (in

^{6.} Please refer to Application Note M538 for surface mounting instructions.

^{7.} Derate linearly to 0 W @ 125°C case temperature.

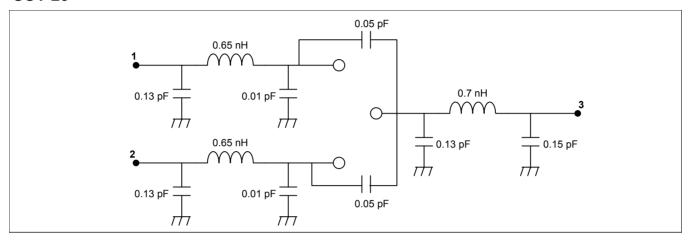


Surface Mount Low Barrier Schottky Diode

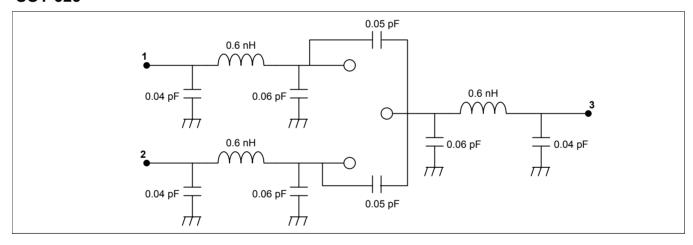
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Circuit Models

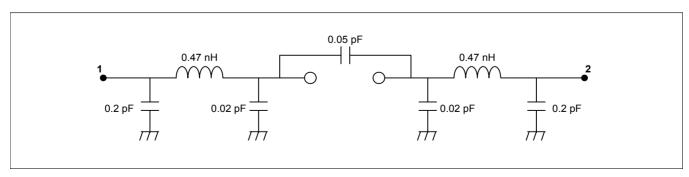
SOT-23



SOT-323



SOD-323



3

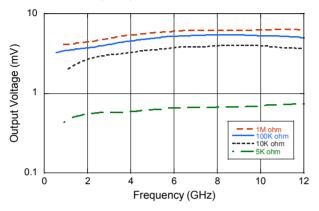


Surface Mount Low Barrier Schottky Diode

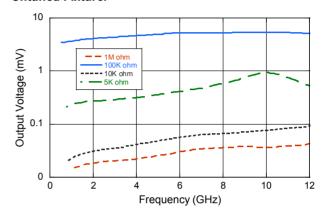
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Typical Performance Curves @ +25°C in Chip Form, Mounted on a Microstrip Fixture

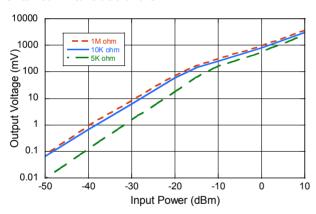
Detector Output Voltage vs. Frequency and Load Resistance at -30 dBm. Diode Forward Biased at 20μ A. Untuned Fixture (50 Ω)



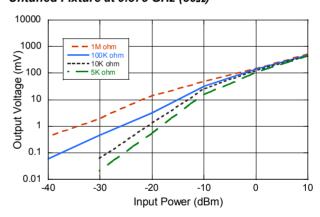
Detector Output Voltage vs. Frequency and Load Resistance at -30 dBm. Diode at Zero Bias. Untuned Fixture.



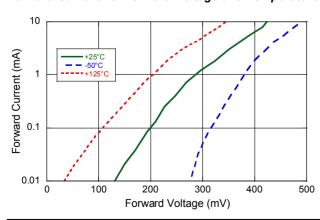
Detector Output Voltage vs. Input Power and Load Resistance. Diode Forward Biased at 20μ A. Untuned Fixture at 9.375 GHz.



Detector Output Voltage vs. Input Power and Load Resistance. Diode at Zero Bias. Untuned Fixture at 9.375 GHz (50Ω)



Forward Current vs. Forward Voltage and Temperature



Noise Figure vs. Lo Power at 9.375 GHz Tuned Fixture



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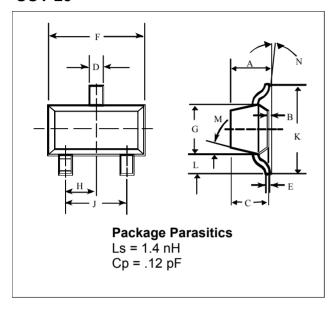


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Case Styles

SOT-23

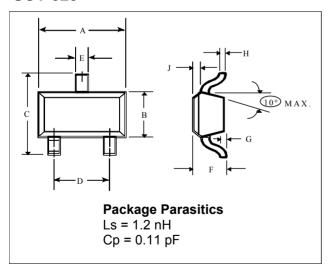


SOT-23 (Case Style 287)

Dim.	Inc	hes	Millimeters		
Dilli.	Min. Max.		Min.	Max.	
Α	_	0.048	_	1.22	
В	_	0.008	_	0.20	
С	_	0.040	_	1.00	
D	0.013	0.020	0.35	0.50	
Е	0.003	0.006	0.08	0.15	
F	0.110	0.119	2.80	3.00	
G	0.047	0.056	1.20	1.40	
Н	0.037	typical	0.95 typical		
J	0.075	typical	1.90 typical		
K	_	0.103	_	2.60	
L	_	0.024	_	0.60	
Dim.	Gradient				
М	10° max. ³				
N	2°30°				

^{3.} Applicable on all sides

SOT-323



SOT-323 (Case Style 1146)

Dim.	Inc	hes	Millimeters		
Dilli.	Min.	Max.	Min.	Max.	
Α	0.063	0.087	1.6	2.2	
В	0.045	0.053	1.15	1.35	
С	C 0.079 0.087		2.0	2.2	
D	D 0.047 0.055 1.2		1.2	1.4	
Е	0.008	0.016	0.2	0.4	
F	0.031	0.039	0.8	1.0	
G	_	0.004	_	0.1	
Н	0.003	0.006	0.08	0.15	
J	0.004	0.010	0.1	0.25	

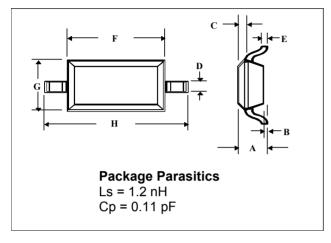


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Case Styles (Cont'd)

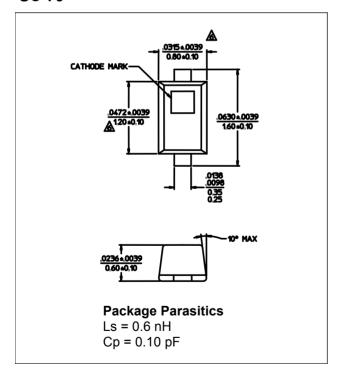
SOD-323



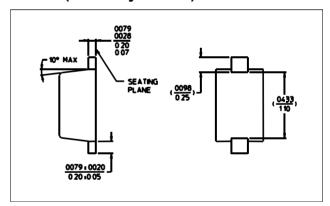
SOD-323 (Case Style 1141)

Dim.	Incl	hes	Millimeters		
Dilli.	Min.	Min. Max.		Max.	
Α	_	0.043	_	1.1	
В	_	0.004	_	0.1	
С	_	0.008	_	0.2	
D	0.010	0.016	0.25	0.4	
E	0.003	0.006	0.08	0.15	
F	0.063	0.075	1.6	1.9	
G	0.045	0.057	1.15	1.45	
Н	0.091	0.106	2.3	2.7	

SC-79



SC-79 (Case Style 1279)





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Spice Model Parameters

IS = 3 x 10-8 A	M = 0.50
RS = 11Ω	EG = 0.69 eV
N = 1.05	BV = 5.0 V
TT = 0 S	IBV = 1 x 10 - 5 A
Cj(0) = 0.13 x 10 - 12 pF	
Cpar = 0.14 x 10 -12 pF	
VJ = 0.40 V	

Typical Scattering Parameters (S11)

MA4E2054A Chip Form, Mounted on a Microstrip Fixture (no DC bias)

Freq.	-30	dBm	-3 0	dBm	0 d	IBm	3 d	lBm
GHz	MAG	PHASE	MAG	PHASE	MAG	PHASE	MAG	PHASE
0.50	0.993	-7.6	0.812	-7.0	0.597	-4.6	0.387	-0.9
1.00	0.994	-15.1	0.843	-14.7	0.632	-13.9	0.411	-11.3
1.50	0.993	-21.4	0.807	-21.7	0.596	-22.3	0.386	-22.4
2.00	0.997	-27.1	0.791	-26.0	0.580	-23.1	0.383	-16.4
2.50	0.994	-33.2	0.795	-31.5	0.579	-27.6	0.378	-18.5
3.00	0.994	-41.3	0.755	-42.7	0.548	-45.2	0.342	-48.6
3.50	0.992	-48.6	0.727	-52.2	0.524	-55.8	0.318	-60.8
4.00	0.997	-56.5	0.713	-58.9	0.502	-59.5	0.296	-56.3
4.50	0.987	-66.4	0.696	-67.1	0.464	-67.7	0.235	-62.6
5.00	0.971	-74.7	0.634	-79.8	0.386	-86.2	0.167	-94.9
5.50	0.965	-83.1	0.614	-88.6	0.354	-91.4	0.131	-98.7
6.00	0.980	-96.0	0.547	-103.5	0.292	-107.0	0.072	-117.2
6.50	0.974	-110.3	0.514	-120.1	0.248	-129.5	0.041	163.9
7.00	0.941	-123.7	0.450	-137.4	0.235	-150.8	0.070	145.2
7.50	0.957	-138.9	0.430	-158.1	0.247	178.0	0.152	120.6
8.00	0.969	-155.6	0.404	-178.8	0.260	150.1	0.218	102.5
8.50	0.933	-171.5	0.405	162.2	0.294	129.9	0.278	92.0
9.00	0.932	170.9	0.391	143.1	0.310	110.8	0.344	84.4
9.50	0.943	152.8	0.410	128.2	0.318	97.9	0.343	68.7
10.00	0.931	132.2	0.504	108.9	0.394	83.3	0.399	56.9



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